

**ZTX1049A**
**25V NPN MEDIUM POWER TRANSISTOR IN E-LINE**
**Features**

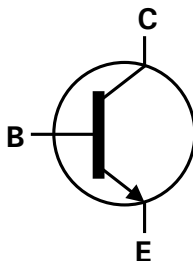
- $BV_{CEO} > 25V$
- $I_C = 4A$  High Continuous Collector Current
- $I_{CM} = 20A$  Peak Pulse Current
- $T_J$  up to  $200^{\circ}C$  for High Temperature Operation
- Low Saturation Voltage  $< 75mV @ 1A$
- $P_D = 1W$  Power dissipation
- **Lead-Free Finish; RoHS compliant (Note 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Applications**

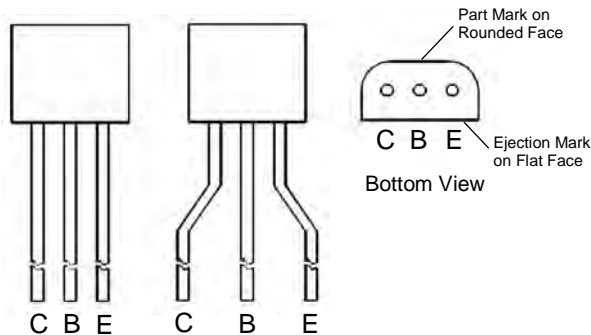
- LCD Backlight Converters
- Emergency Lighting
- DC-DC Converters

 E-Line  
 (TO-92 Compatible)


Flat Face View



Device Symbol



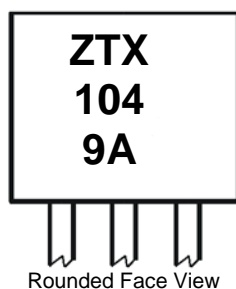
Rounded Face View

Pin-Out Configuration

**Ordering Information (Note 4)**

Part Number	Marking	Case	Leads	Quantity
ZTX1049ASTZ	ZTX1049A	E-Line	Joggled	2,000 taped per Ammo Box
ZTX1049A	ZTX1049A	E-Line	Straight	4,000 loose in a Box

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain  $<900ppm$  bromine,  $<900ppm$  chlorine ( $<1500ppm$  total Br + Cl) and  $<1000ppm$  antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


ZTX1049A = Product type Marking Code

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Continuous Collector Current	I <sub>C</sub>	4	A
Peak Pulse Current	I <sub>CM</sub>	20	A
Base Current	I <sub>B</sub>	500	mA

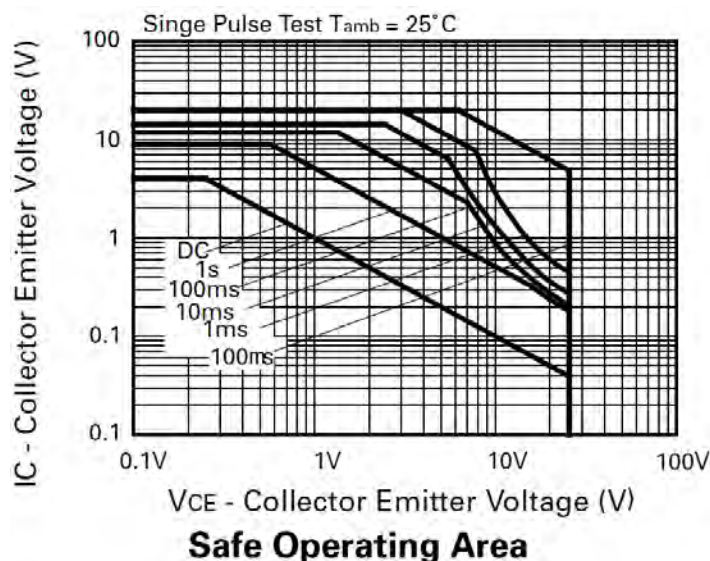
**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

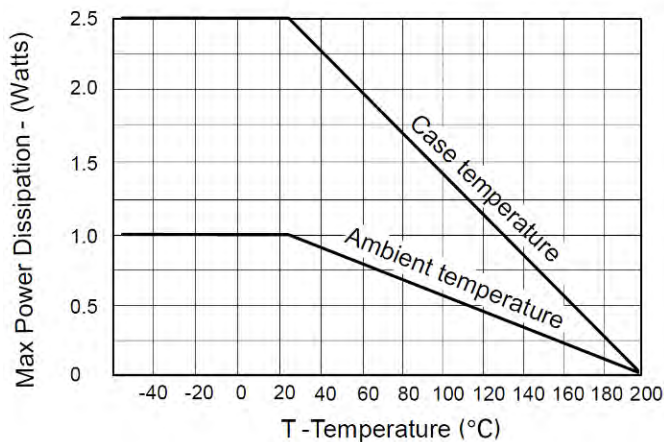
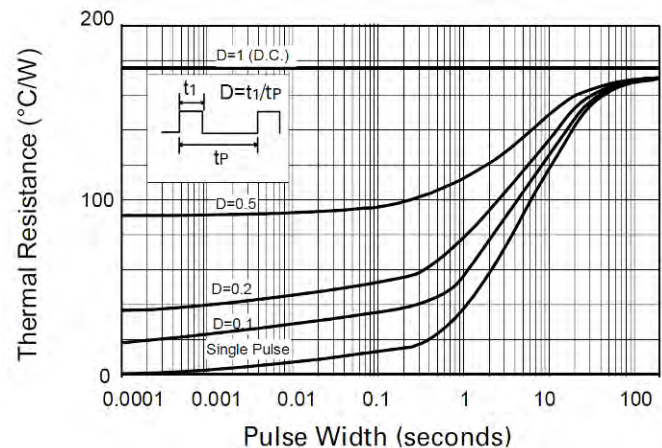
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P <sub>D</sub>	1.5	W
Power Dissipation (Note 6)	P <sub>D</sub>	1	W
Thermal Resistance Junction to Ambient (Note 5)	R <sub>θJA</sub>	116	°C/W
Thermal Resistance Junction to Ambient (Note 6)	R <sub>θJA</sub>	175	°C/W
Thermal Resistance Junction to Lead (Note 7)	R <sub>θJL</sub>	63.75	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +200	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
- For a through-hole device mounted at the seating plane (2.5mm lead length) with the collector lead on 25mm X 25mm 1oz weight copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Same as note (5), except the device is mounted on minimum recommended pad layout with 12mm lead length from the bottom of package to the board.
  - Thermal resistance from junction to solder-point at the seating plane (2.5mm from the bottom of package along the collector lead).
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

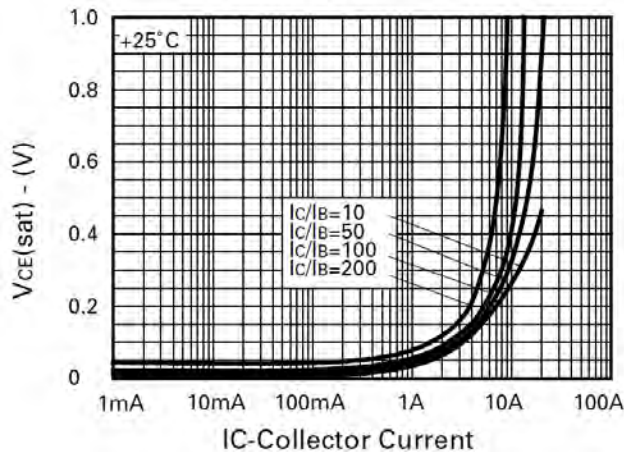
**Thermal Characteristics and Derating Information**



**Derating curve**

**Maximum transient thermal impedance**
**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

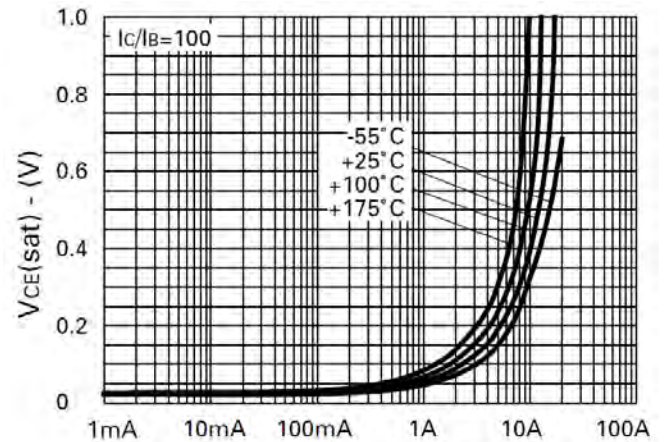
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	80	120	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CES}$	80	120	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 9)	$BV_{CEO}$	25	30	—	V	$I_C = 10\text{mA}$
Collector-Emitter Breakdown Voltage	$BV_{CEV}$	80	120	—	V	$I_C = 100\mu\text{A}$ , $V_{EB} = 1\text{V}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5	8.75	—	V	$I_E = 100\mu\text{A}$
Collector Cut-off Current	$I_{CBO}$	—	0.3	10	nA	$V_{CB} = 50\text{V}$
Collector Emitter Cut-off Current	$I_{CES}$	—	0.3	10	nA	$V_{CES} = 50\text{V}$
Emitter Cut-off Current	$I_{EBO}$	—	0.3	10	nA	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	30 60 125 155	45 80 180 220	mV	$I_C = 500\text{mA}$ , $I_B = 10\text{mA}$ $I_C = 1\text{A}$ , $I_B = 10\text{mA}$ $I_C = 2\text{A}$ , $I_B = 10\text{mA}$ $I_C = 4\text{A}$ , $I_B = 50\text{mA}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	890	950	mV	$I_C = 4\text{A}$ , $I_B = 50\text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	—	820	900	mV	$I_C = 4\text{A}$ , $V_{CE} = 2\text{V}$
DC Current Gain (Note 9)	$h_{FE}$	250 300 300 200 35	430 450 450 350 70	— — 1200 — —	—	$I_C = 10\text{mA}$ , $V_{CE} = 2\text{V}$ $I_C = 0.5\text{A}$ , $V_{CE} = 2\text{V}$ $I_C = 1\text{A}$ , $V_{CE} = 2\text{V}$ $I_C = 4\text{A}$ , $V_{CE} = 2\text{V}$ $I_C = 20\text{A}$ , $V_{CE} = 2\text{V}$
Current Gain-Bandwidth Product (Note 9)	$f_T$	—	180	—	MHz	$V_{CE} = 10\text{V}$ , $I_C = 50\text{mA}$ $f = 50\text{MHz}$
Output Capacitance (Note 9)	$C_{obo}$	—	45	60	pF	$V_{CB} = 10\text{V}$ , $f = 1\text{MHz}$
Turn-On Times	$t_{on}$	—	125	—	ns	$I_C = 4\text{A}$ , $I_B = 40\text{mA}$ , $V_{CC} = 10\text{V}$
Turn-Off Times	$t_{off}$	—	380	—	ns	$I_C = 4\text{A}$ , $I_B = 40\text{mA}$ , $V_{CC} = 10\text{V}$

 Notes: 9. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$

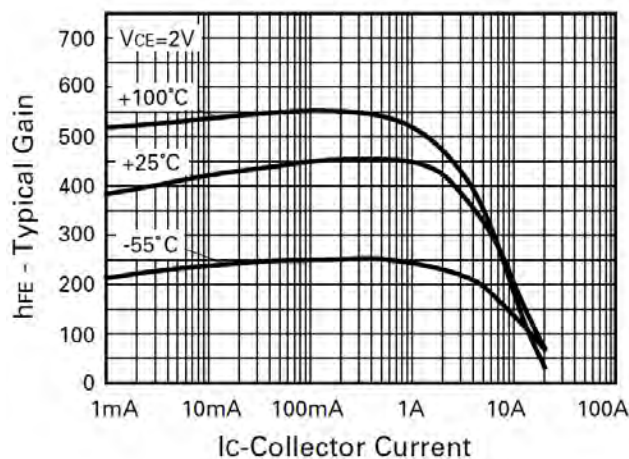
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



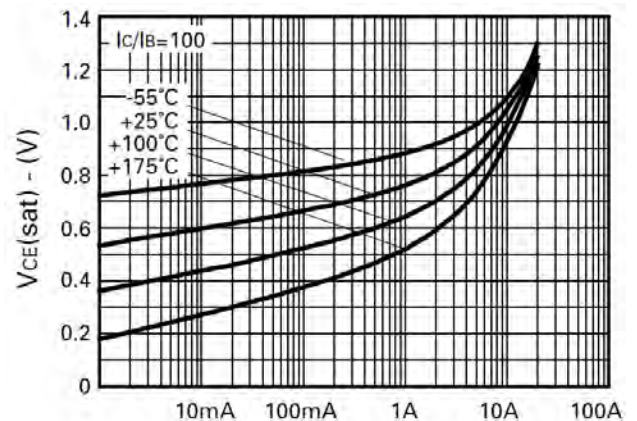
**$V_{CE(sat)}$  v  $I_C$**



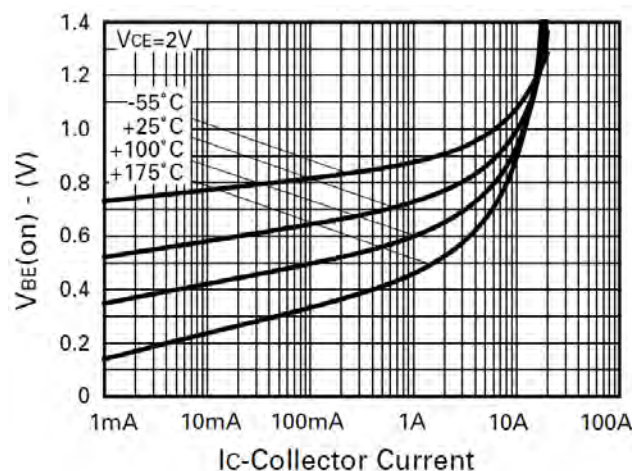
**$V_{CE(sat)}$  v  $I_C$**



**$h_{FE}$  v  $I_C$**



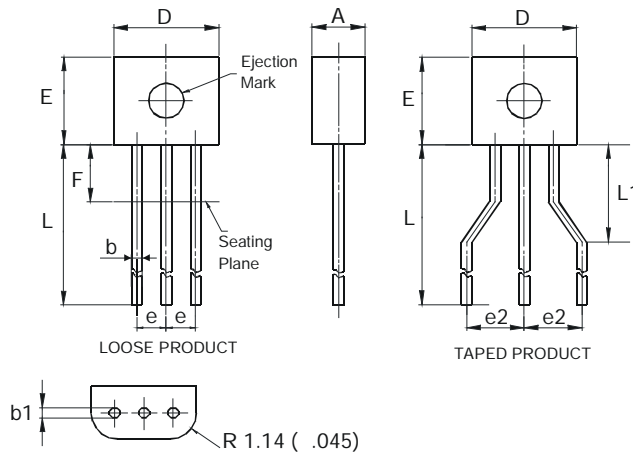
**$V_{BE(sat)}$  v  $I_C$**



**$V_{BE(on)}$  v  $I_C$**

## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



E-Line			
Dim	Min	Max	Typ
A	2.16	2.41	—
b	0.41	0.495	—
b1	0.41	0.495	—
D	4.37	4.77	—
E	3.61	4.01	—
e	—	—	1.27
e2	—	—	2.54
F	—	2.50	—
L	13.00	13.97	—
L1	2.50	3.50	—
All Dimensions in mm			



**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2013, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)